

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











600V, 4A

Integrated Power Module for Small Appliance Motor Drive Applications

Description

IRSM506-076 and IRSM516-076 are 3-phase Integrated Power Modules (IPM) designed for advanced appliance motor drive applications such as energy efficient fans and pumps. These advanced IPMs offers a combination of low $V_{\text{CE(sat)}}$ Trench IGBT technology and the industry benchmark half-bridge high voltage, rugged driver in a familiar package. The modules are optimized for low EMI characteristics.

IRSM506-076 includes temperature feedback while IRSM516-076 does not.

Features

- 600V 3-phase inverter including high voltage gate drivers
- Integrated bootstrap functionality
- Low 1.7V V_{CE(sat)} (max, 25°C, 1A) Trench IGBT
- Under-voltage lockout for all channels
- Matched propagation delay for all channels
- Temperature feedback via NTC (IRSM506-076 only)
- Optimized dV/dt for loss and EMI trade offs
- Open-emitter for single and leg-shunt current sensing
- 3.3V logic compatible
- Driver tolerant to negative transient voltage (-Vs)
- Advanced input filter with shoot-through protection
- Rugged design for PM fan and pump motors
- Isolation 1900V_{RMS}, 1min

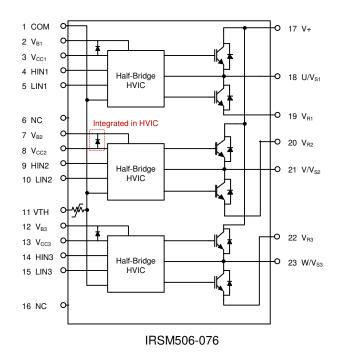


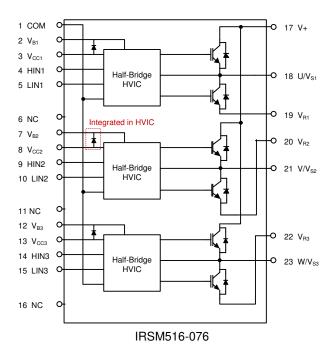


Base Part Number	NTC	Package Type	Standard Pac	k	Orderable Part Number
base Part Number	NIC		Form	Quantity	Orderable Part Number
	Yes	SOP23	Tube	240	IRSM506-076PA
IRSM506-076 Yo		DIP23	Tube	240	IRSM506-076DA
		DIP23A	Tube	240	IRSM506-076DA2
		SOP23	Tube	240	IRSM516-076PA
IRSM516-076	No	DIP23	Tube	240	IRSM516-076DA
		DIP23A	Tube	240	IRSM516-076DA2



Internal Electrical Schematic





Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the module may occur. These are not tested at manufacturing. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table.

Symbol	Description	Min	Max	Unit
V _{CES} / V _{RRM}	IGBT/ FW Diode Blocking Voltage		600	V
I _O @ T _C =25°C	DC Output Current per IGBT		4.0	Δ.
I _{OP} @ T _C =25°C	Pulsed Output Current per IGBT (Note 1)		15	A
P _d @ T _C =25°C	Maximum Power Dissipation per IGBT		16	W
V _{ISO}	Isolation Voltage (1min)		1900	V _{RMS}
TJ	Operating Junction Temperature	-40	150	°C
T _C	Operating Case Temperature	-40	150	°C
T _S	Storage Temperature	-40	150	°C
V _{S1,2,3}	High Side Floating Supply Offset Voltage	V _{B1,2,3} - 20	V _{B1,2,3} +0.3	V
V _{B1,2,3}	High Side Floating Supply Voltage	-0.3	625	V
V _{CC}	Low Side and Logic Supply voltage	-0.3	25	V
V _{IN}	Input Voltage of LIN, HIN	COM -0.3	V _{CC} +0.3	V

Note 1: Pulse Width = $100\mu s$, Single Pulse



Recommended Operating Conditions

Symbol	Symbol Description		Max	Unit
V+	Positive DC Bus Input Voltage		480	V
V _{S1,2,3}	High Side Floating Supply Offset Voltage	(Note 2)	480	V
V _{B1,2,3}	High Side Floating Supply Voltage	V _S +12	V _S +20	V
V _{CC}	Low Side and Logic Supply Voltage	13.5	16.5	V
V _{IN}	Input Voltage of LIN, HIN, ITRIP, EN, FLT	0	5	٧
Fp	PWM Carrier Frequency		20	kHz

Note 2: Logic operational for Vs from COM-8V to COM+600V. Logic state held for Vs from COM-8V to COM-VBS.

Static Electrical Characteristics

 $(V_{CC}\text{-COM}) = (V_B\text{-}V_S) = 15 \text{ V}. \ T_C = 25^{\circ}\text{C}$ unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to COM and are applicable to all six channels. The V_{CCUV} parameters are referenced to COM. The V_{BSUV} parameters are referenced to V_S .

Symbol	Description	Min	Тур	Max	Units	Conditions
V _{(BR)CES}	Collector to Emitter Breakdown Voltage	600			V	T _J =25°C, I _{LK} =250μA
I _{LKH}	Leakage Current of Each High Side IGBT		5		μΑ	T _J =25°C, V _{CE} =600V
I _{LKL}	Leakage Current of Low Side IGBT Plus Gate Drive IC		10		μΑ	T _J =25°C, V _{CE} =600V
			1.2	1.7		T _J =25°C, V _{CC} =15V, Ic = 1A
V _{CE(ON)}	Collector to Emitter Saturation Voltage		1.3		V	$T_J=150$ °C, $V_{CC}=15$ V, $I_{C}=1$ A (Note 3)
V _{FM}	Diode Forward Voltage Drop		1.05		V	T _J =25°C, V _{CC} =15V, I _F =1A
$V_{IN,th+}$	Positive Going Input Threshold	2.2			V	
$V_{\text{IN,th}}$	Negative Going Input Threshold			0.8	V	
V _{CCUV+} , V _{BSUV+}	V_{CC} and V_{BS} Supply Under-Voltage, Positive Going Threshold	10.4	11.1	11.8	V	
V _{CCUV-} , V _{BSUV-}	V _{CC} and V _{BS} supply Under-Voltage, Negative Going Threshold	10.2	10.9	11.6	V	
V _{CCUVH} , V _{BSUVH}	V _{CC} and V _{BS} Supply Under-Voltage Lock-Out Hysteresis		0.2		V	
I _{QBS}	Quiescent V _{BS} Supply Current V _{IN} =0V		42	60	μΑ	
I _{QBS, ON}	Quiescent V _{BS} Supply Current V _{IN} =4V		42	60	μΑ	
I _{QCC}	Quiescent V _{CC} Supply Current V _{IN} =0V		1.7	4	mA	
I _{QCC, ON}	Quiescent V _{CC} Supply Current V _{IN} =4V		1.8	4	mA	
I _{IN+}	Input Bias Current V _{IN} =4V		4.6	18	μΑ	V _{IN} =3.3V
I _{IN-}	Input Bias Current V _{IN} =0V			2	μΑ	V _{IN} =0V
R _{BR}	Internal Bootstrap Equivalent Resistor Value		200		Ω	T _J =25°C

Note 3: Characterized, not tested at manufacturing



Dynamic Electrical Characteristics

 $(V_{CC}\text{-COM}) = (V_{B}\text{-}V_{S}) = 15 \text{ V}. \ T_{C} = 25^{\circ}\text{C}$ unless otherwise specified.

Symbol	Description	Min	Тур	Max	Units	Conditions
T _{ON}	Input to Output Propagation Turn-On Delay Time		0.7	1.5	μs	I _D =120mA, V+=30V
T _{OFF}	Input to Output Propagation Turn-Off Delay Time		0.8	1.5	μs	See Fig.1
T _{FIL,IN}	Input Filter Time (HIN, LIN)	200	300		ns	V _{IN} =0 & V _{IN} =3.3V
DT	Deadtime Inserted		400		ns	V _{IN} =0 & V _{IN} =3.3V without external deadtime
Eon	Turn-on switching energy loss		16		μJ	
E _{OFF}	Turn-off switching energy loss		10		μJ	V ₊ =320V, I _D =0.5A, L=40mH, T _C =25°C (Note 4)
E _{REC}	Recovery energy loss		5		μJ	10-20 0 (11010 1)
E _{ON,150}	Turn-on switching energy loss		35		μJ	
E _{OFF,150}	Turn-off switching energy loss		21		μJ	V ₊ =320V, I _D =0.5A, L=40mH, T _C =150°C (Note 4)
E _{REC,150}	Recovery energy loss		13		μJ	.0 .00 0 (

Note 4: Characterized, not tested at manufacturing

Thermal and Mechanical Characteristics

Symbol	Description	Min	Тур	Max	Units	Conditions
R _{th(J-C)}	Junction to Case Thermal Resistance, one IGBT		7.2		°C/W	High Side V-Phase IGBT (Note 5)
R _{th(J-C)}	Junction to Case Thermal Resistance, one diode		9.1		°C/W	High Side V-Phase Diode (Note 5)

Note 5: Characterized, not tested at manufacturing. Case temperature (T_C) point shown in Figure 2.

Internal NTC - Thermistor Characteristics (IRSM506-076 Only)

Symbol	Description	Min	Тур	Max	Units	Conditions
R ₂₅	Resistance		47		kΩ	T _C =25°C, ±5% tolerance
R ₁₂₅	Resistance		1.41		kΩ	T _C =125°C
В	B-constant (25-50°C)		4050		K	±2% tolerance (Note 6)
Temperati	ure Range	-40		125	°C	

Note 6: See application notes for usage



Qualification Information[†]

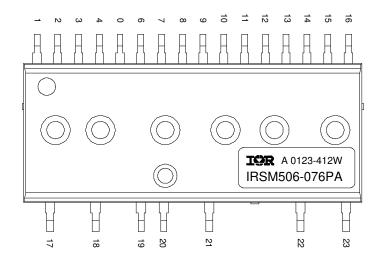
Qualification	on Level	Industrial ^{††}
Moisture S	ensitivity Level	MSL3 ^{†††}
RoHS Com	pliant	Yes
UL Certifie	d	Yes – File Number E252584
ESD	Machine Model	Class B
ESD	Human Body Model	Class 2

- † Qualification standards can be found at International Rectifier's web site http://www.irf.com/
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† SOP23 package only. Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.



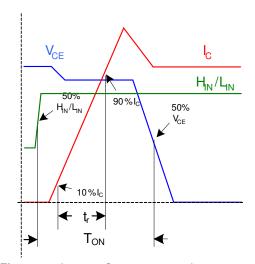
Module Pin-Out Description

Pin	Name	Description
1	COM	Logic Ground
2	V _{B1}	High Side Floating Supply Voltage 1
3	V _{CC1}	15V Supply 1
4	HIN1	Logic Input for High Side Gate Driver - Phase 1
5	LIN1	Logic Input for Low Side Gate Driver - Phase 1
6	NC	Not Connected
7	V _{B2}	High Side Floating Supply Voltage 2
8	V _{CC2}	15V Supply 2
9	HIN2	Logic Input for High Side Gate Driver - Phase 2
10	LIN2	Logic Input for Low Side Gate Driver - Phase 2
11	V_{TH}	Thermistor Output (IRSM506-076DA)
11	NC	Not Connected (IRSM516-076DA)
12	V _{B3}	High Side Floating Supply Voltage 3
13	V _{CC3}	15V Supply 3
14	HIN3	Logic Input for High Side Gate Driver - Phase 3
15	LIN3	Logic Input for Low Side Gate Driver - Phase 3
16	NC	Not Connected
17	V+	DC Bus Voltage Positive
18	U/V _{S1}	Output - Phase 1, High Side Floating Supply Offset 1
19	V _{R1}	Phase 1 Low Side Emitter
20	V _{R2}	Phase 2 Low Side Emitter
21	V/V _{S2}	Output - Phase 2, High Side Floating Supply Offset 2
22	V _{R3}	Phase 3 Low Side Emitter
23	W/V _{S3}	Output - Phase 3, High Side Floating Supply Offset 2





Referenced Figures



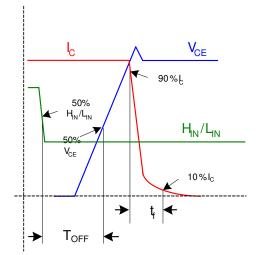


Figure 1a: Input to Output propagation turn-on delay time.

Figure 1b: Input to Output propagation turn-off delay time.

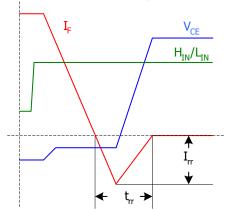


Figure 1c: Diode Reverse Recovery.

Figure 1: Switching Parameter Definitions

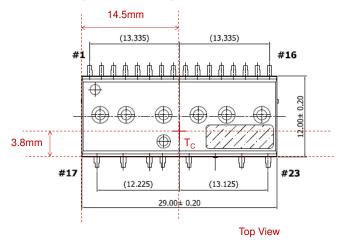


Figure 2: T_C measurement point for R_{th(j-C)}



Application Notes

A basic application schematic is shown below.

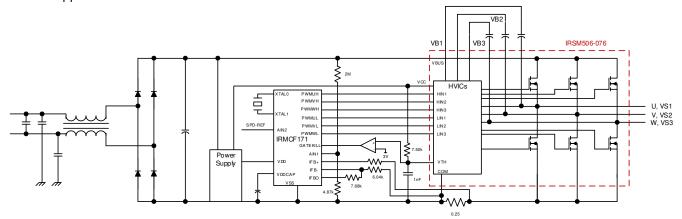


Figure 3: Basic sensor-less motor drive circuit connection. Motor is connected to U, V, W

A complete reference design board for running any permanent magnet motor via sensorless sinusoidal control is available. The board – photo below – features the µIPM™-DIP module and the iMotion™ digital control IC. Reference design kits are available on the Infineon website (irf.com > Design Resources > Reference Designs > Intelligent Power Modules)



Figure 4: Reference design board featuring the µIPM™-DIP module and the iMotion™ IRMCF171 digital control IC



Figures 5-7 show the typical current capability for this module at specified conditions. In all tests, the application board – the IRMCS1071-1-D reference board – was placed in a box to prevent cooling from ambient airflow. Figure 5 is derived from using a heat sink that maintains T_C at 125°C. Figures 6-7 represent current capability for the module as used without any heat sink. ΔT_{JA} represents the difference in temperature between the junction of the high-side V-phase IGBT and the ambient, measured 10cm above and 6cm away from the board. Ambient temperature kept within 28-29°C.

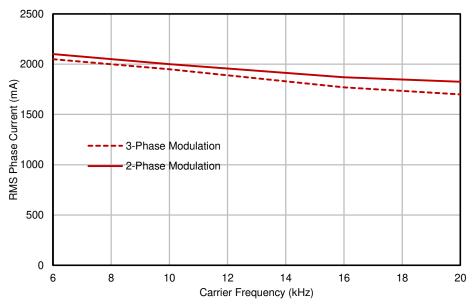


Figure 5: Maximum sinusoidal phase current vs PWM switching frequency with a heat sink. Space Vector Modulation, V+=320V, T_A=28°C, T_J=150°C, T_C=125°C

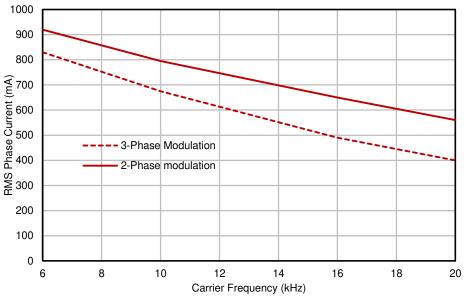


Figure 6: Maximum sinusoidal phase current vs PWM switching frequency, no heat sink. Space Vector Modulation, V+=320V, T_A=28°C, T_J=128°C



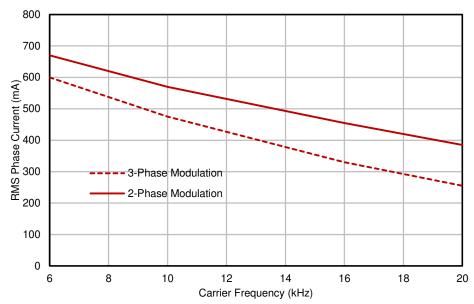


Figure 7: Maximum sinusoidal phase current vs PWM switching frequency, no heat sink. Space Vector Modulation, V+=320V, T_A=28°C, T_J=98°C

The module contains an NTC – connected between COM and the V_{TH} pin – which can be used to monitor the temperature of the module. The NTC is effectively a resistor whose value decreases as the temperature rises. The NTC resistance can be calculated at any temperature as follows:

$$R_{TH}=R_{25}e^{\left[B\left(\frac{1}{T_{TH}}-\frac{1}{T_{25}}\right)\right]}$$
 , where R_{25} is 47k Ω and B is 4050K

An external resistor network is connected to the NTC, the simplest of which is one resistor pulled up to V_{CC} as shown in Figure 3. The V_{TH} vs NTC temperature, T_{TH} curve for this configuration is shown in Figure 8 below. The min, typical and max curves result from the NTC having a $\pm 5\%$ tolerance on its resistance and $\pm 2\%$ tolerance on the B-parameter.

Figure 9 shows the thermistor temperature, T_{TH} plotted against the high-side V-phase junction temperature, T_{J} for a module without a heat sink. It is thus advisable to shut down the module when T_{TH} reaches 125°C.



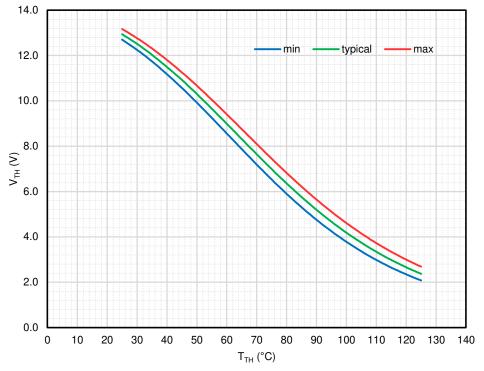


Figure 8: V_{TH} vs T_{TH} with V_{TH} pin pulled up to V_{CC} with a 7.50k Ω (1%, 100ppm) resistor. A 15V, 1% variation in V_{CC} is assumed.

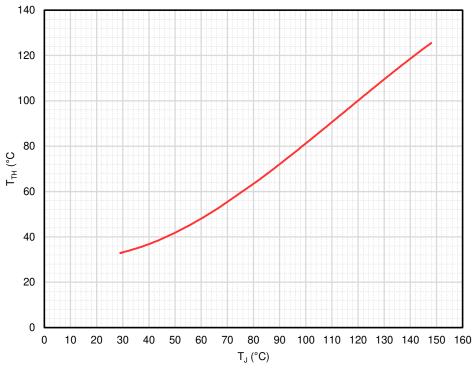


Figure 9: T_{TH} vs T_J for a module without a heat sink. V_{CC} =15.4V, R=7.50k Ω



The μ IPMTM-DIP module series features an advanced filter for input pins, LIN and HIN. The filter rejects noise spikes and short pulses with widths shorter than $T_{\text{FIL.IN}}$ as illustrated in Figure 10 below.

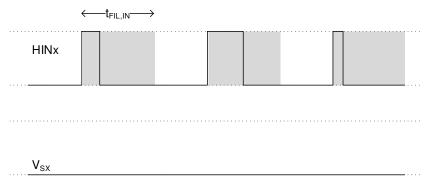


Figure 10: Advanced input filter rejects noise spikes on a logic 0-level HIN signal. The behavior is similar for noise spikes on logic 1-level signals

The advanced input filter maintains the pulse duration for pulses slightly longer than $t_{\text{FIL,IN}}$. Figure 11 illustrates this feature.

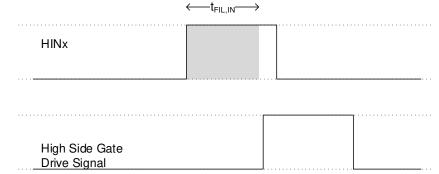


Figure 11: Advanced input filter maintains the pulse duration for pulses longer than tFIL,IN

The module series also features shoot-through protection. If a logic 1-level signal is applied to LIN and HIN simultaneously, the IGBTs of the corresponding inverter leg are kept off. For overlapping logic 1-level LIN & HIN signals, a deadtime of duration DT is applied. The input-output logic table is shown below.

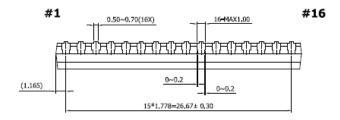
HINx	LINx	V _{Sx}
1	0	V+
0	1	0
0	0	*
1	1	*\$

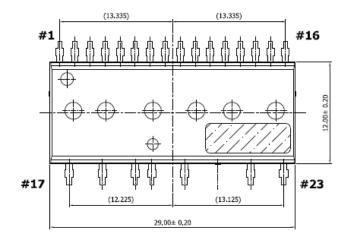
^{*} Voltage depends on direction of phase current

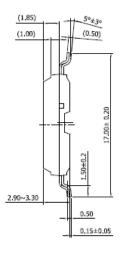
^{\$} Integrated shoot-through protection prevents simultaneous turn on of high side and low side IGBTs of the same inverter leg

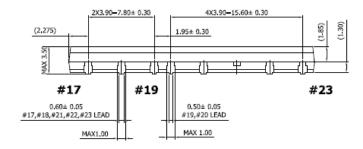


SOP23 Package Outline





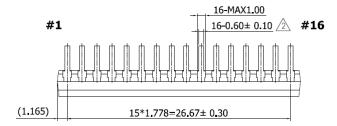


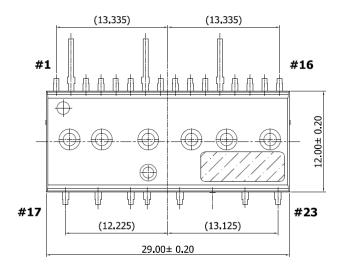


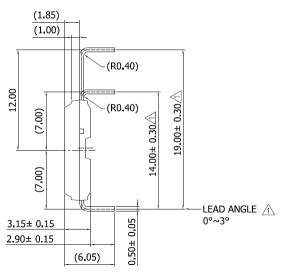
Dimensions in mm

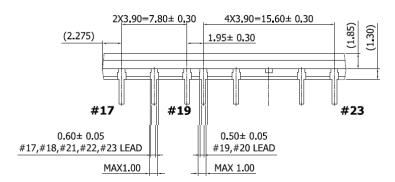


DIP23A Package Outline





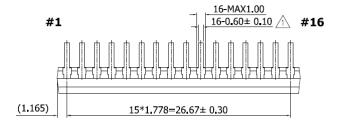


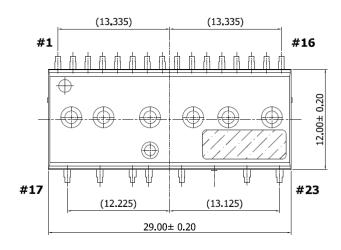


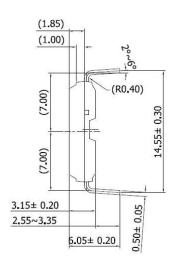
Dimensions in mm

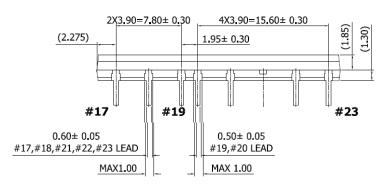


DIP23 Package Outline





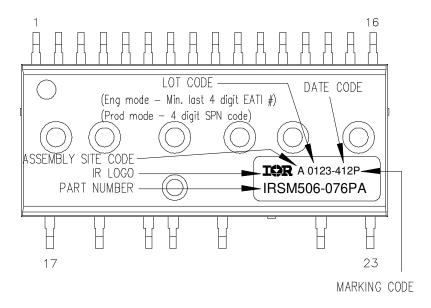




Dimensions in mm



Top Marking



Marking Code

P = Pb Free; Y = Engineering Samples

Date Code

YWW format, where Y = least significant digit of the production year , WW = two digits representing the week of the production year

Revision History

Feb 9 Updated header & footer designs; added application notes related to advanced input filter



Published by Infineon Technologies AG 81726 München, Germany © Infineon Technologies AG 2015 All Rights Reserved.

IMPORTANT NOTICE

The information given in this document shall in <u>no event</u> be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

For further information on the product, technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies office (www.infineon.com).

WARNINGS

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may <u>not</u> be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.